

# RGW40TK65D 650V 20A Field Stop Trench IGBT

V <sub>CES</sub>	650V
Ι <sub>C (100°C)</sub>	16A
V <sub>CE(sat) (Typ.)</sub>	1.5V
P <sub>D</sub>	61W

## Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Speed Switching
- 3) Low Switching Loss & Soft Switching
- 4) Built in Very Fast & Soft Recovery FRD
- 5) Pb free Lead Plating ; RoHS Compliant

#### Application

PFC

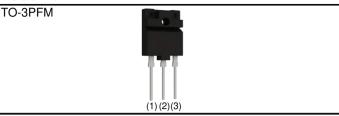
UPS

Welding

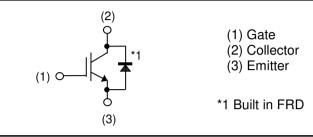
Solar Inverter

IH

#### Outline



#### Inner Circuit



#### Packaging Specifications

	Packaging	Tube
	Reel Size (mm)	-
Tuno	Tape Width (mm)	-
Туре	Basic Ordering Unit (pcs)	450
	Packing Code	C11
	Marking	RGW40TK65D

#### •Absolute Maximum Ratings (at T<sub>C</sub> = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V <sub>CES</sub>	650	V
Gate - Emitter Voltage		V <sub>GES</sub>	±30	V
Collector Current	$T_{\rm C} = 25^{\circ}{\rm C}$	Ι <sub>C</sub>	27	Α
Collector Current	$T_{\rm C} = 100^{\circ}{\rm C}$	Ι <sub>C</sub>	16	Α
Pulsed Collector Current		I <sub>CP</sub> *1	80	Α
Diode Forward Current	$T_{\rm C} = 25^{\circ}{\rm C}$	١ <sub>F</sub>	27	Α
Diode Forward Current	$T_{C} = 100^{\circ}C$	١ <sub>F</sub>	16	Α
Diode Pulsed Forward Current		I <sub>FP</sub> <sup>*1</sup>	80	Α
Power Dissinction	$T_{\rm C} = 25^{\circ}{\rm C}$	P <sub>D</sub>	61	W
Power Dissipation	$T_{\rm C} = 100^{\circ}{\rm C}$	P <sub>D</sub>	30	W
Operating Junction Temperature		T <sub>j</sub>	-40 to +175	°C
Storage Temperature		T <sub>stg</sub>	-55 to +175	°C

\*1 Pulse width limited by  $T_{jmax.}$ 

#### •Thermal Resistance

Parameter	Sumbol	Values			Unit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal Resistance IGBT Junction - Case	$R_{\theta(j\text{-}c)}$	-	-	2.44	°C/W
Thermal Resistance Diode Junction - Case	$R_{\theta(j\text{-}c)}$	-	-	2.79	°C/W

### ●IGBT Electrical Characteristics (at T<sub>j</sub> = 25°C unless otherwise specified)

Parameter	Symbol Conditions		Values			Unit
	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector - Emitter Breakdown Voltage	BV <sub>CES</sub>	$I_{\rm C}$ = 10µA, $V_{\rm GE}$ = 0V	650	-	-	V
Collector Cut - off Current	I <sub>CES</sub>	$V_{CE} = 650V, V_{GE} = 0V$	-	-	10	μA
Gate - Emitter Leakage Current	I <sub>GES</sub>	$V_{GE} = \pm 30V, V_{CE} = 0V$	-	-	±200	nA
Gate - Emitter Threshold Voltage	$V_{\text{GE(th)}}$	V <sub>CE</sub> = 5V, I <sub>C</sub> = 13.3mA	5.0	6.0	7.0	V
Collector - Emitter Saturation Voltage	V <sub>CE(sat)</sub>	$I_{C} = 20A, V_{GE} = 15V,$ $T_{j} = 25^{\circ}C$ $T_{j} = 175^{\circ}C$	-	1.5 1.85	1.9 -	V

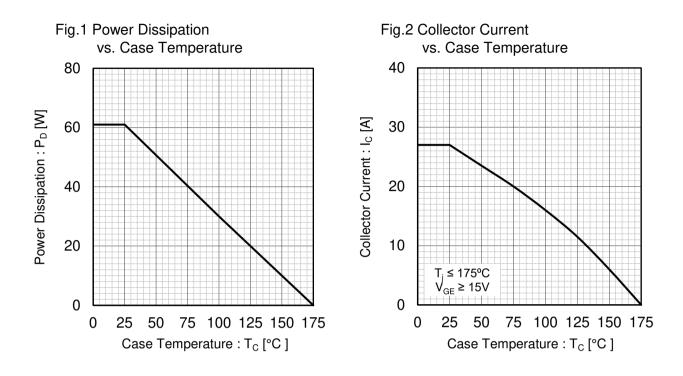
#### RGW40TK65D

# •IGBT Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol Conditions	Conditions	Values			Unit	
		Conditions	Min.	Тур.	Max.	Unit	
Input Capacitance	C <sub>ies</sub>	$V_{CE} = 30V,$	-	1680	-		
Output Capacitance	C <sub>oes</sub>	$V_{GE} = 0V,$	-	47	-	pF	
Reverse transfer Capacitance	C <sub>res</sub>	f = 1MHz	-	31	-		
Total Gate Charge	Qg	V <sub>CE</sub> = 400V,	-	59	-		
Gate - Emitter Charge	$Q_{ge}$	I <sub>C</sub> = 20A,	-	13	-	nC	
Gate - Collector Charge	$Q_{gc}$	$V_{GE} = 15V$	-	23	-		
Turn - on Delay Time	t <sub>d(on)</sub>		-	33	-		
Rise Time	t <sub>r</sub>	$I_{C} = 20A, V_{CC} = 400V,$ $V_{GE} = 15V, R_{G} = 10\Omega,$	-	10	-	ns	
Turn - off Delay Time	t <sub>d(off)</sub>	$V_{GE} = 15V, n_G = 1002,$ $T_i = 25^{\circ}C$	-	76	-		
Fall Time	t <sub>f</sub>	Inductive Load	-	63	-		
Turn - on Switching Loss	E <sub>on</sub>	*E <sub>on</sub> include diode reverse recovery	-	0.33	-	ml	
Turn - off Switching Loss	E <sub>off</sub>	· · · · · · · · · · · · · · · · · · ·	-	0.30	-	mJ	
Turn - on Delay Time	t <sub>d(on)</sub>		-	31	-		
Rise Time	t <sub>r</sub>	$I_{C} = 20A, V_{CC} = 400V,$ $V_{GE} = 15V, R_{G} = 10\Omega,$	-	10	-	20	
Turn - off Delay Time	t <sub>d(off)</sub>	$T_i = 175^{\circ}C$	-	102	-	ns	
Fall Time	t <sub>f</sub>	Inductive Load	-	76	-		
Turn - on Switching Loss	E <sub>on</sub>	*E <sub>on</sub> include diode reverse recovery	-	0.34	-	mJ	
Turn - off Switching Loss	E <sub>off</sub>		-	0.43	-	IIIJ	
Reverse Bias Safe Operating Area	RBSOA	$\begin{split} I_{C} &= 80 \text{A}, \ V_{CC} = 520 \text{V}, \\ V_{P} &= 650 \text{V}, \ V_{GE} = 15 \text{V}, \\ R_{G} &= 100 \Omega, \ T_{j} = 175^{\circ} \text{C} \end{split}$	FU	ILL SQUA	RE	-	

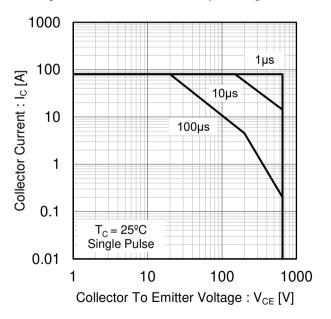
# •FRD Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

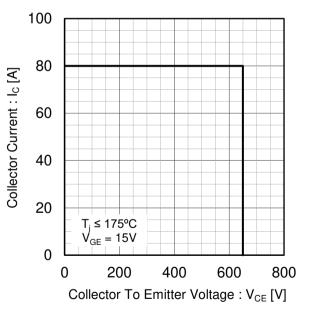
Parameter	Cumbal	Conditions	Values			1.1
	Symbol		Min.	Тур.	Max.	Unit
		I <sub>F</sub> = 20A,				
Diode Forward Voltage	V <sub>F</sub>	$T_j = 25^{\circ}C$	-	1.45	1.9	V
		T <sub>j</sub> = 175°C	-	1.55	-	
Diode Reverse Recovery Time	t <sub>rr</sub>		-	92	-	ns
Diode Peak Reverse Recovery Current	I <sub>rr</sub>	$I_F = 20A,$ $V_{CC} = 400V,$ $di_F/dt = 200A/\mu s,$ $T_j = 25^{\circ}C$	-	6.7	-	A
Diode Reverse Recovery Charge	Q <sub>rr</sub>		-	0.34	-	μC
Diode Reverse Recovery Energy	E <sub>rr</sub>		-	14.1	-	μJ
Diode Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 20A, V <sub>CC</sub> = 400V, di <sub>F</sub> /dt = 200A/µs, T <sub>j</sub> = 175°C	-	123	-	ns
Diode Peak Reverse Recovery Current	I <sub>rr</sub>		-	7.8	-	A
Diode Reverse Recovery Charge	Q <sub>rr</sub>		-	0.59	-	μC
Diode Reverse Recovery Energy	E <sub>rr</sub>		-	30.7	-	μJ

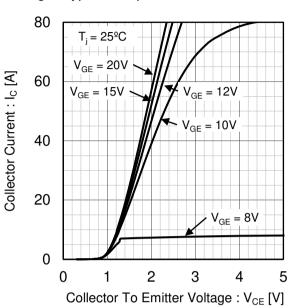


### Fig.3 Forward Bias Safe Operating Area



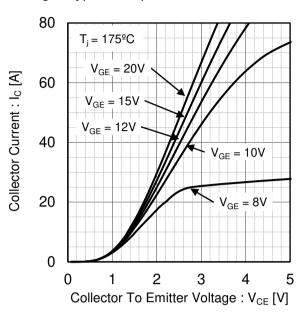


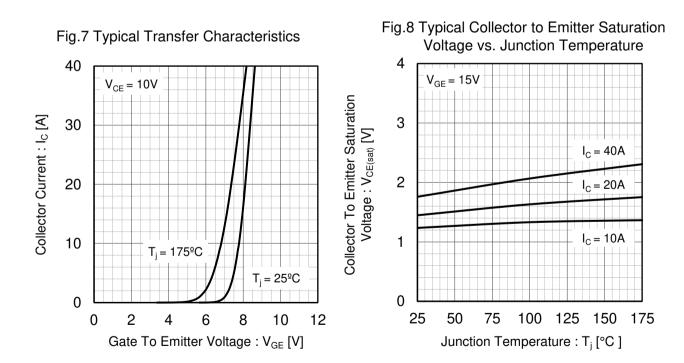


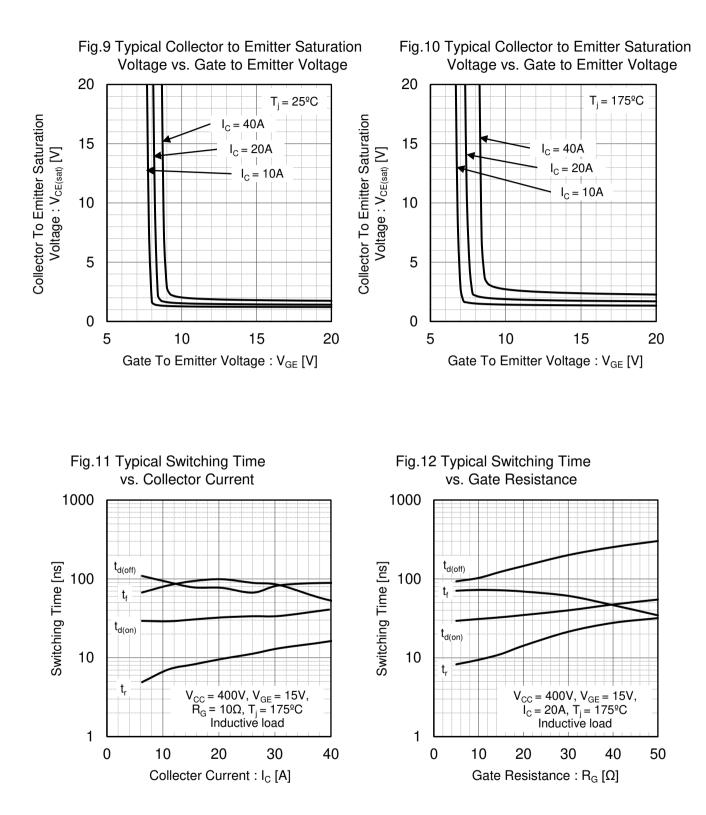


#### Fig.5 Typical Output Characteristics

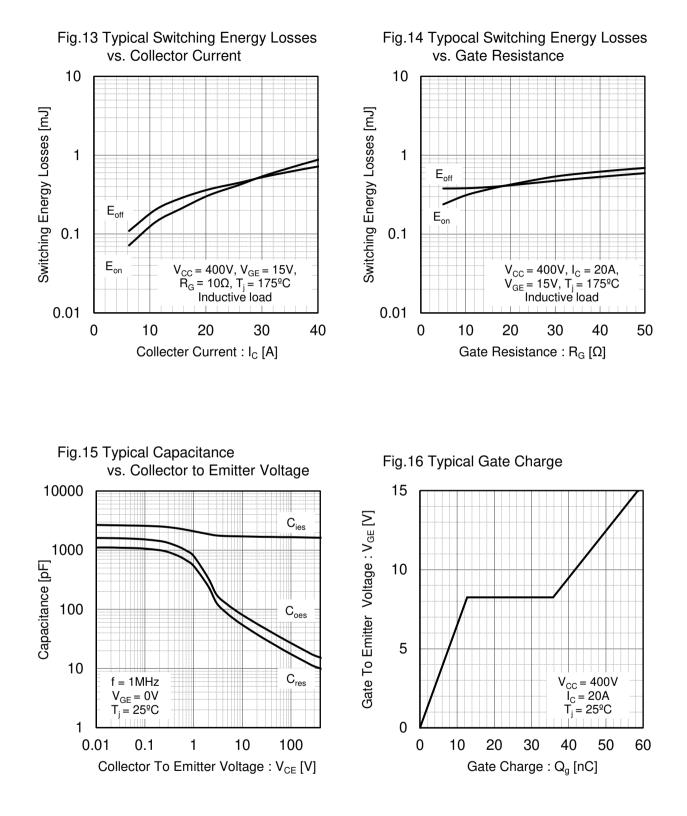
Fig.6 Typical Output Characteristics

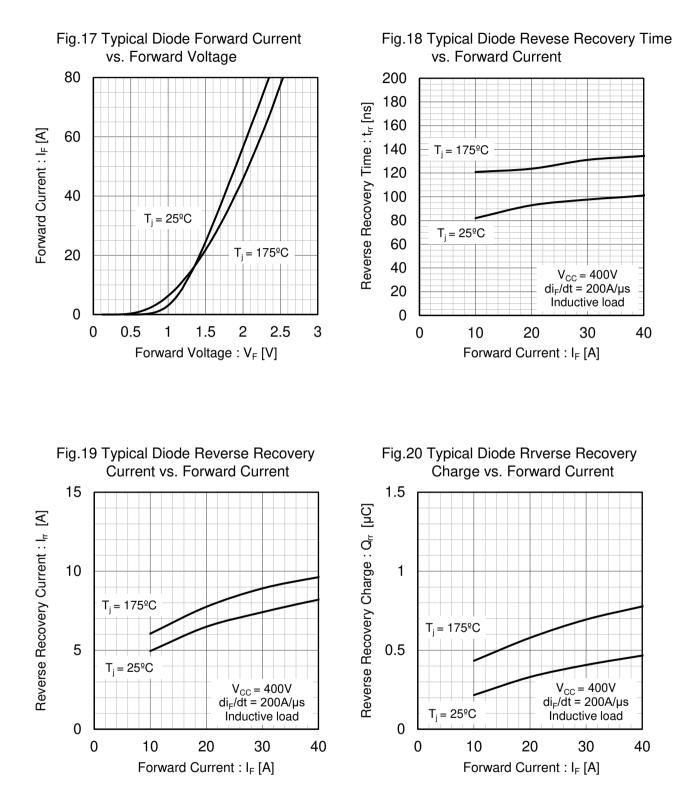


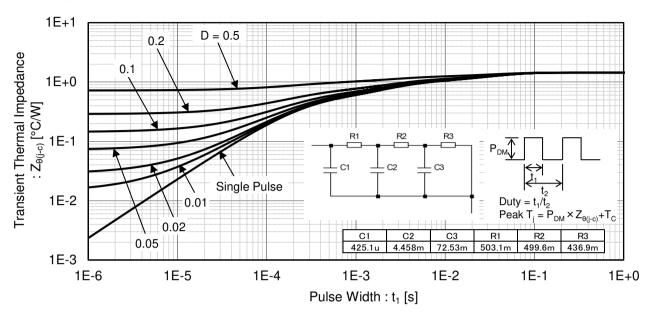




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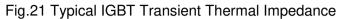
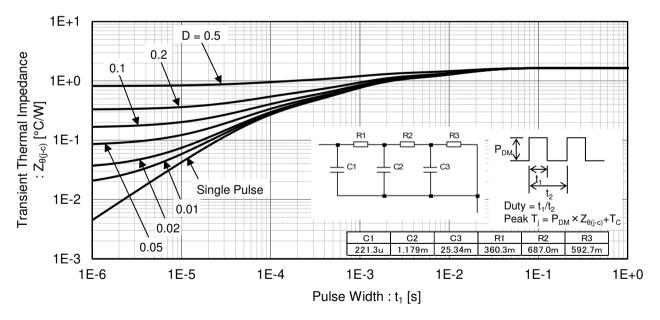


Fig.22 Typical Diode Transient Thermal Impedance



#### Inductive Load Switching Circuit and Waveform

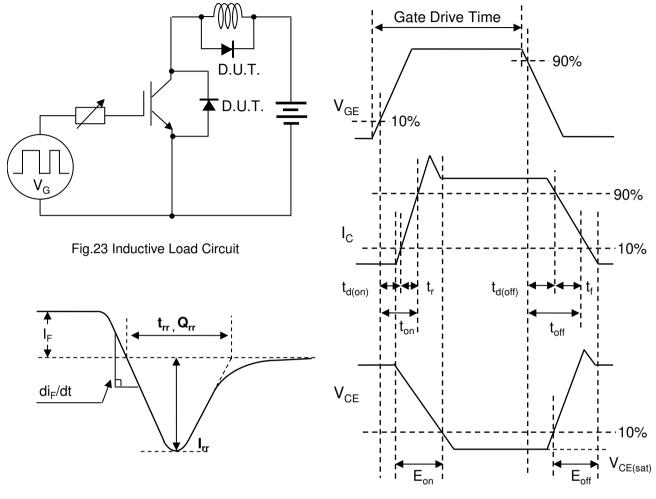


Fig.25 Diode Reverse Recovery Waveform

Fig.24 Inductive Load Waveform

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